## NSN 5961-01-387-3039

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View Online at https://aerobasegroup.com/nsn/5961-01-387-3039 **Inclosure Material:** Metal **Overall Length:** Between 0.160 inches and 0.180 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-205af **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 drain to gate voltage and 100.0 forward voltage, average and 20.0 gate to source voltage **Current Rating Per Characteristic:** 14.00 amperes off-state current, peak **Power Rating Per Characteristic:** 15.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Test Data Document:** 08748-tr169 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 81349-mil-prf-19500/556 government specification Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig:

Mil-std (military Standard):

Mil-prf-19500 spec.

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